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DMG7N65SJ3

### Product Summary

BV <sub>DSS</sub>	RDS(ON) Max	I <sub>D</sub> Tc = +25°С
650V	$1.4\Omega @ V_{GS} = 10V$	5.5A

## **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Motor Control
- Backlighting
- DC-DC Converters
- Power Management Functions

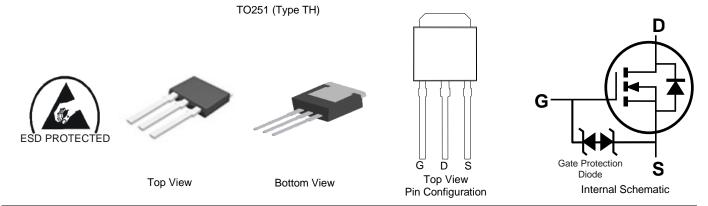
#### N-CHANNEL ENHANCEMENT MODE MOSFET

### **Features and Benefits**

- Low On-Resistance
- High BVDSS Rating for Power Application
- Low Input Capacitance
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

### **Mechanical Data**

- Case: TO251
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.33 grams (Approximate)



### Ordering Information (Note 4)

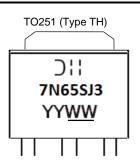
Case	Packaging
TO251 (Type TH)	75 Pieces / Tube
-	

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**



 D ↓ ↓= Manufacturer's Marking 7N65SJ3= Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 20 = 2020) <u>WW</u> = Week Code (01 to 53)



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	<b>Value</b> 650	Unit V
Drain-Source Voltage	V <sub>DSS</sub>			
Gate-Source Voltage		Vgss	±30	V
Continuous Drain Current (Note 5) V <sub>GS</sub> = 10V	T <sub>C</sub> = +25°C T <sub>C</sub> = +100°C	lD	5.5 3.7	A
Continuous Drain Current (Note 5) V <sub>GS</sub> = 10V	T <sub>A</sub> = +25°C	ID	0.7	А
Maximum Body Diode Forward Current (Note 5)	•	ls	5.5	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		Ідм	10	A
Avalanche Current (Note 6)	L = 60mH	las	1.7	A
Avalanche Energy (Note 6)	L = 60mH	Eas	87	mJ
Peak Diode Recovery dv/dt (Note 6)	•	dv/dt	3	V/ns

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Total Power Dissipation (Note 5)	Tc = +25°C	Da	125	W	
Total Fower Dissipation (Note 5)	Tc = +100°C	PD	50	vv	
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	PD	1.8	W	
Thermal Resistance, Junction to Ambient (Note 5)		R <sub>0JA</sub>	70	°C/W	
Thermal Resistance, Junction to Case (Note 5)	Rejc	1	C/VV		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

### Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	Cymbol		176	max	onic		
Drain-Source Breakdown Voltage	BVDSS	650			V	Vgs = 0V, Id = 250µA	
Zero Gate Voltage Drain Current	IDSS		—	1	μA	$V_{DS} = 650V, V_{GS} = 0V$	
Gate-Source Leakage	lgss		_	10	μA	$V_{GS} = \pm 24V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)	•		•	•		·	
Gate Threshold Voltage	V <sub>GS(TH)</sub>	2	3	4	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	RDS(ON)	_	1.1	1.4	Ω	V <sub>GS</sub> = 10V, I <sub>D</sub> = 2.5A	
Diode Forward Voltage	Vsd	_	0.84	1.5	V	$V_{GS} = 0V, I_S = 5A$	
DYNAMIC CHARACTERISTICS (Note 6)	•		•	•		·	
Input Capacitance	Ciss	_	886	—	pF		
Output Capacitance	Coss	_	62	—		V <sub>DS</sub> = 50V, f = 1MHz, V <sub>GS</sub> = 0V	
Reverse Transfer Capacitance	Crss	_	8.8	_			
Gate Resistance	Rg		1.36		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg		25			V <sub>DS</sub> = 480V, I <sub>D</sub> = 5A, V <sub>GS</sub> = 10V	
Gate-Source Charge	Qgs	_	3.5		nC		
Gate-Drain Charge	Qgd	_	12.4	_		VGS = 10V	
Turn-On Delay Time	td(ON)	_	10			V <sub>DS</sub> = 300V, V <sub>GS</sub> = 10V, R <sub>G</sub> = 4.7Ω, I <sub>D</sub> = 2.5A	
Turn-On Rise Time	t <sub>R</sub>	_	11	_	ns		
Turn-Off Delay Time	t <sub>D(OFF)</sub>		36	_			
Turn-Off Fall Time	tF		15	_			
Body Diode Reverse Recovery Time	trr	_	245	_	ns	$V_{DS}$ =100V, I <sub>F</sub> = 5A,	
Body Diode Reverse Recovery Charge	QRR	_	1.89	_	μC	dl/dt = 100A/µs	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Guaranteed by design. Not subject to production testing.
Short duration pulse test used to minimize self-heating effect.

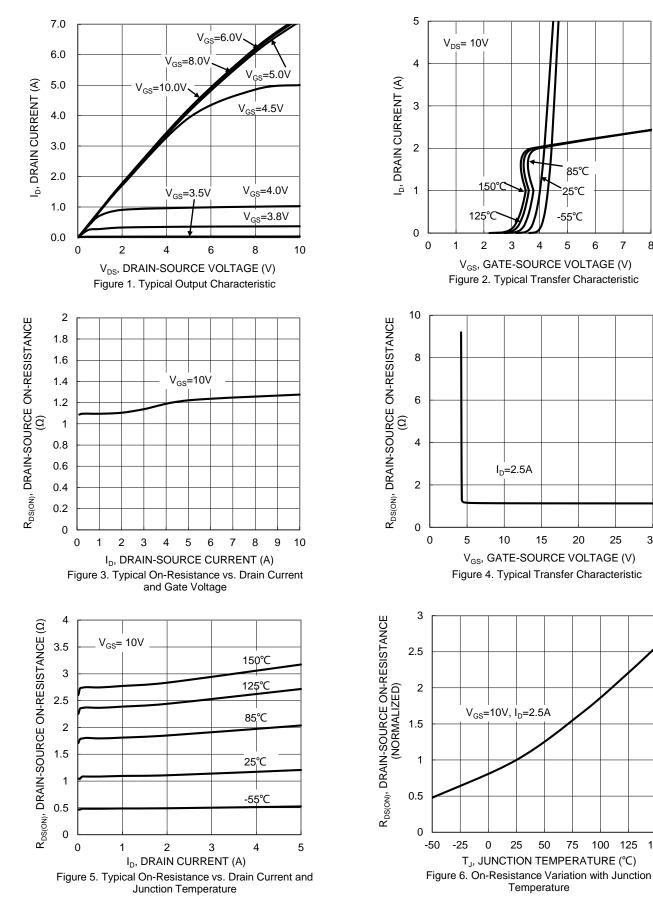


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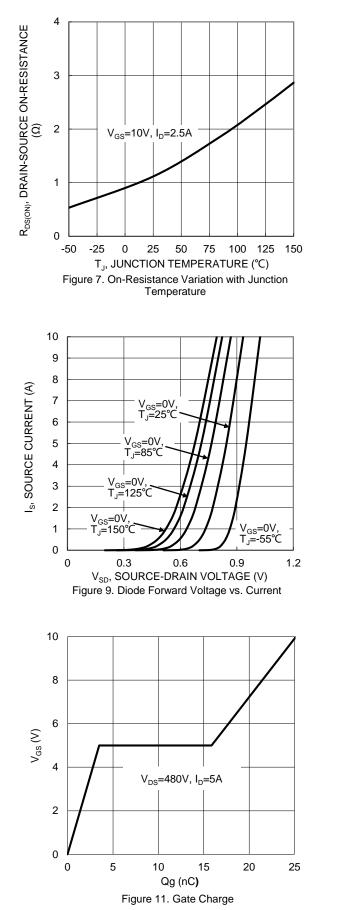
8

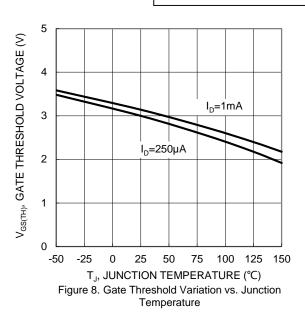


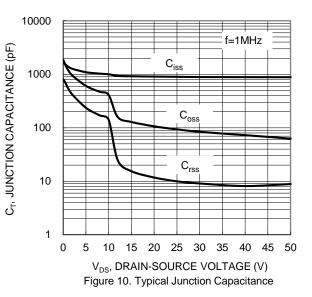
150

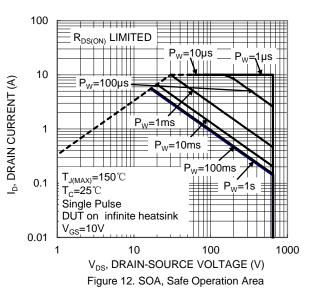
125





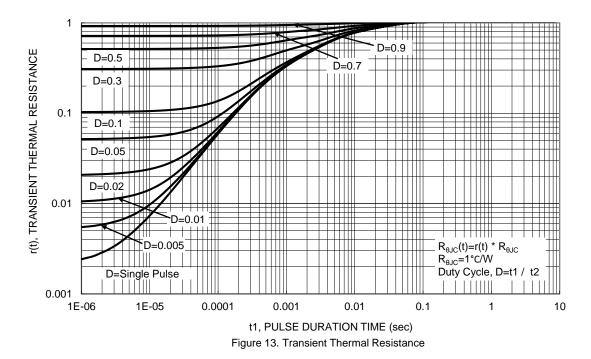










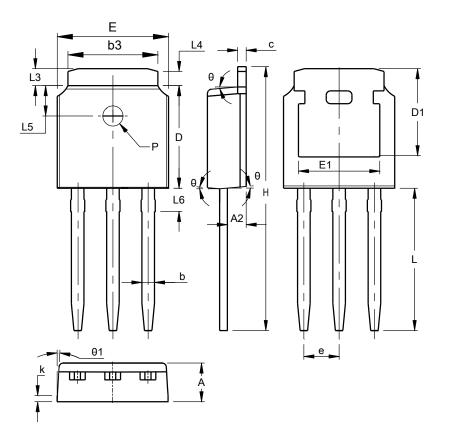




# Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.





TO251 (Type TH)						
Dim	Min	Max	Тур			
Α	2.20	2.40	2.30			
A2	0.97	1.17	1.07			
b	0.68	0.90	0.78			
b3	5.20	5.50	5.33			
С	0.43	0.63	0.53			
D	5.98	6.22	6.10			
D1	5	.30 RE	F			
е	2.	286 BS	C			
E	6.40	6.80	6.60			
E1	4.63	5.03	4.83			
Н	16.22	16.82	16.52			
k	C	0.40REF				
L	9.15	9.65	9.40			
L3	0.88	1.28	1.02			
L4	0	0.75 REF				
L5	1.65	1.95	1.80			
L6	0.85	1.25	1.05			
PØ	1.20					
θ	5°	9°	7°			
θ1	5°	9°	7°			
All Dimensions in mm						



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